NSN 5962-01-088-1630

Memory Microcircuit - Page 1 of 2

AeroBase Group

View Online at https://aerobasegroup.com/nsn/5962-01-088-1630

Body Length:	
0.840 inches	
Body Width:	
Between 0.220 inches and 0.310 inches	
Body Height:	
Between 0.140 inches and 0.185 inches	
Maximum Power Dissipation Rating:	
715.0 milliwatts	
Operating Tempurature Range:	
-55.0/+125.0 degrees celsius	
Storage Tempurature Range:	
-65.0/+150.0 degrees celsius	
End Application:	
Radar set, type no. An/fps-115	
Features Provided:	
Hermetically sealed and monolithic and positive outputs and 3-state output and bipolar and programmable and programmed and w/disable	e
and w/enable and w/storage and w/decoded output and w/buffered output and schottky	
Inclosure Material:	
Ceramic and glass	
Inclosure Configuration:	
Dual-in-line	
Output Logic Form:	
Transistor-transistor logic	
Input Circuit Pattern:	
10 input	
Case Outline Source And Designator:	
D-2 mil-m-38510	
Terminal Surface Treatment:	
Solder	
Voltage Rating And Type Per Characteristic:	
5.5 volts power source	
Time Rating Per Chacteristic:	
85.00 nanoseconds propagation delay time, low to high level output and 85.00 nanoseconds propagation delay time, high to low level	
output	
Memory Device Type:	
Rom	
Memory Capacity:	
Unknown	
Test Data Document:	
49956-952369 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc	c.;
excludes any specification, standard or other document that may be referenced in a basic governing drawing)	
Terminal Type And Quantity:	

16 printed circuit

Shelf Life:

NI/o

NSN 5962-01-088-1630

Memory Microcircuit - Page 2 of 2

Unit Of Measure:

Demilitarization:

Yes - demil/mli

Fiig:

A458a0

